## NSN 5961-01-204-2850

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-204-2850 **Inclosure Material:** Glass **Overall Length:** 0.115 inches **Overall Diameter:** 0.092 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.0 collector to emitter voltage, dc **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Yes - demil/mli

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